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Team Nexperia



PMEG4002EL 40 V, 0.2 A low V_F MEGA Schottky barrier rectifierRev. 02 — 11 March 2009Prod

Product data sheet

Product profile 1.

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD882 leadless ultra small Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Forward current: $I_F \le 0.2 \text{ A}$
- Reverse voltage: V_R ≤ 40 V
- Low forward voltage
- Leadless ultra small SMD plastic package
- Power dissipation comparable to SOT23

1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- Low voltage rectification
- Blocking diodes
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current		-	-	0.2	А
V _R	reverse voltage		-	-	40	V



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2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	
2	anode	1 2	1 <u>-</u> 2 sym001
		Transparent top view	

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Ord	ering infor	mation	
Type number	Package		
	Name	Description	Version
PMEG4002EL	-	leadless ultra small plastic package; 2 terminals; body $1.0 \times 0.6 \times 0.5$ mm	SOD882

4. Marking

Table 4. Marking	
Type number	Marking code
PMEG4002EL	F4

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	40	V
l _F	forward current		-	0.2	А
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \delta \le 0.25$	-	1	A
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	-	3	А
Tj	junction temperature		<u>[1]</u> _	150	°C
T _{amb}	ambient temperature		<u>[1]</u> –65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_{F(AV)}$ rating are available on request.

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6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	<u>[1][2]</u> _	-	500	K/W

- [1] Refer to SOD882 standard mounting conditions (footprint), FR4 Printed-Circuit Board (PCB) with 60 μ m copper strip line.
- [2] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses. Nomograms for determining the reverse power losses P_R and $I_{F(AV)}$ rating are available on request.

7. Characteristics

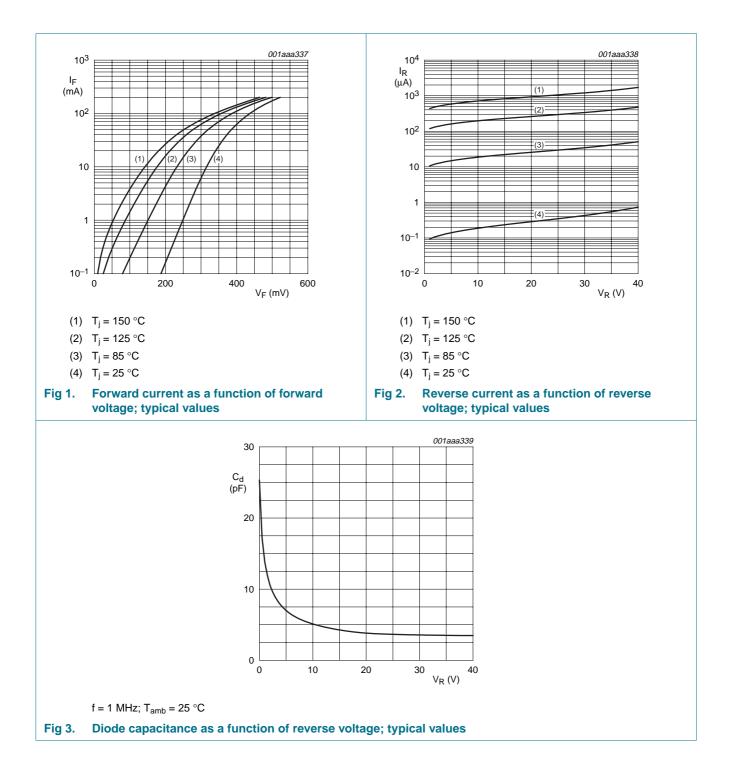
Table 7. Characteristics

 $T_{amb} = 25 \circ C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 0.1 mA		190	220	mV
		$I_F = 1 \text{ mA}$		250	290	mV
		I _F = 10 mA		320	360	mV
		I _F = 100 mA		440	500	mV
		I _F = 200 mA		520	600	mV
I _R	reverse current		<u>[1]</u>			
		V _R = 25 V		0.3	0.5	μΑ
		V _R = 40 V		0.7	10	μΑ
C _d	diode capacitance	V _R = 1 V; f = 1 MHz		14	20	рF

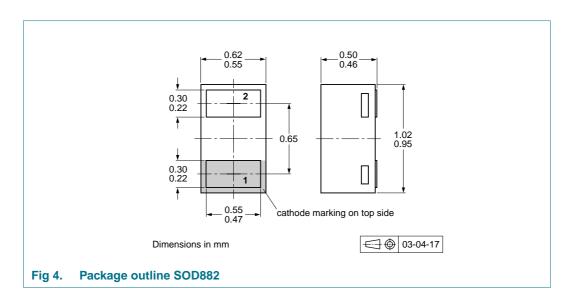
[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

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8. Package outline



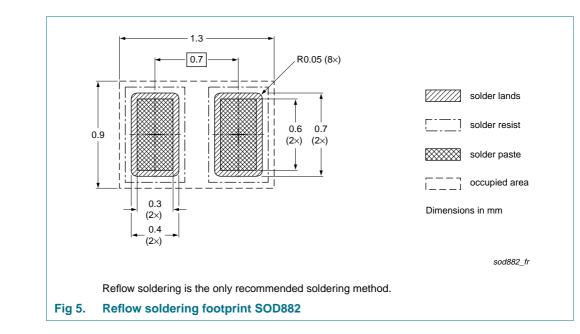
9. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
PMEG4002EL	SOD882	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see Section 13.



10. Soldering

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11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG4002EL_2	20090311	Product data sheet	-	PMEG4002EL_1
Modifications:		of this data sheet has beer of NXP Semiconductors.	redesigned to comply v	vith the new identity
	 Legal texts 	have been adapted to the r	new company name whe	ere appropriate.
	 Figure 4: su 	perseded by minimized pa	ckage outline drawing	
	Section 9 "F	Packing information": addec	1	
	Section 10	'Soldering": added		
	Section 12	Legal information": update	d	
PMEG4002EL 1	20040217	Product data sheet	-	-

40 V, 0.2 A low V_F MEGA Schottky barrier rectifier

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PMEG4002EL_2
Product data sheet

NXP Semiconductors

PMEG4002EL

40 V, 0.2 A low V_F MEGA Schottky barrier rectifier

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